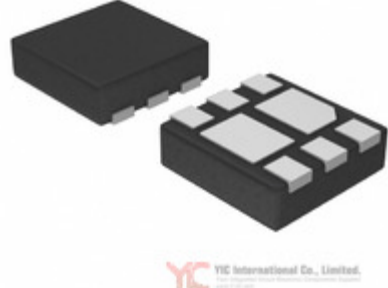

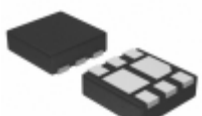
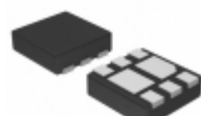
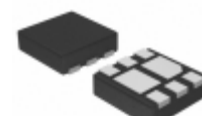
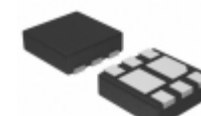
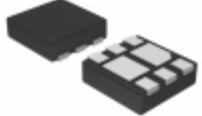
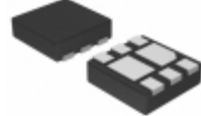

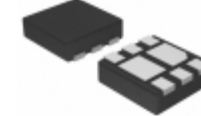
	NTLUD3A50PZTAG	
	Hersteller-Teilenummer:	NTLUD3A50PZTAG
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET 2P-CH 20V 2.8A UDFN
	Datenblätter:	 NTLUD3A50PZTAG.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 6493 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	NTLUD3A50PZTAG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2P-CH 20V 2.8A UDFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	6493 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	6-UDFN Exposed Pad
Supplier Device-Gehäuse	6-UDFN (2x2)
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.8A
Rds On (Max) @ Id, Vgs	50 mOhm @ 4A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	10.4nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	920pF @ 15V
Verpackung	Tape & Reel (TR)
























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Sie können auch interessiert sein:

 NTLUD3A260PZTAG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 1.3A UDFN6	 NTLUD3A50PZTBG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 2.8A UDFN	 NTLUD3191PZTBG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 1.1A 6UDFN	 NTLUD4C26NTBG AMI Semiconductor / ON Semiconductor MOSFET 2 N-CH 30V 9.1A 6UDFN
 NTLUF4189NZTAG AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 1.2A 6UDFN	 NTLUD3A260PZTBG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 1.3A UDFN6	 Not Actual Photo YIC International Co., Limited. NTLTS3107PR2G ON ON DFN-8	 NTLUD3191PZTAG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 1.1A 6UDFN

heiße Teile

Mehr

 12063A100BAT2A	 1808GA200JAT1A	 CC0805Y105ZZOER	 GRM1885C1H182GA01D	 GRM3195C1H102JA01D
 IP-250-CW-TR1	 IXFN82N60P	 NTLGD3502NT1G	 NTLGD3502NT2G	 NTLJ3113PT1G
 NTLJD2105LTBG	 NTLJD3115PT1G	 NTLJD3115PTAG	 NTLJD3119CT1G	 NTLJD3119CTAG
 NTLJD3119CTBG	 NTLJD4116NT1G	 NTLJF3117PT1G	 NTLJF4156NT1G	 NTLJF4156NTAG
 NTLJS2103P	 NTLJS2103PTAG	 NTLJS2103PTBG	 NTLJS3113P	 NTLJS3113PT1G
 NTLJS3113PTAG	 NTLJS3A18PZTWG	 NTLJS4114NT1G	 NTLJS4114NTAG	 NTLJD4901NF
 NTLJD4901NFTWG	 NTLTD7900NR2G	 NTLTD7900ZR2	 NTLTD7900ZR2G	 NTLUD3A260PZTAG
 NTLUF4189NZTAG	 NTLUS3A18PZTAG	 NTLUS3A40PZTAG	 NTLUS3A40PZTBG	 NTLUS3A90PZTAG
 NTLUS4930NTAG	 OPA2356AIDR	 PIP201-12M-3	 PL11004-C	 PM600HVA200-602
 SN74LVC245AZQNR	 SSD20P03-60	 TLE4274GSV33	 TMK063BJ151KP-F	 VE-241-IW

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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